NSN 5961-01-102-1604

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-102-1604 **Inclosure Material:** Plastic **Overall Length:** 0.870 inches **Overall Height:** 0.201 inches **Overall Width:** 0.320 inches **Component Name And Quantity:** 8 semiconductor device diode **Mounting Method:** Press fit **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 75.0 reverse breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute all semiconductor device diode **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 16 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization: No